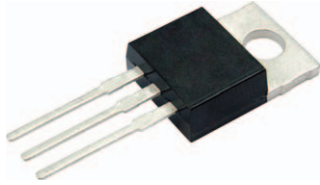
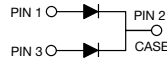


Dual High Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.53 \text{ V}$ at $I_F = 5 \text{ A}$
TMBS®
TO-220AB

V30M100M


FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB

 Molding compound meets UL 94 V-0 flammability rating
 Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	100 V
I_{FSM}	120 A
V_F at $I_F = 15 \text{ A}$ ($T_A = 125 \text{ °C}$)	0.70 V
T_J max.	175 °C
Package	TO-220AB
Diode variations	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V30M100M	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	30
		per diode	15
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	120	A
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +175	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.59	-	V
	$I_F = 7.5\text{ A}$			0.66	-	
	$I_F = 15\text{ A}$			0.85	0.93	
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.53	-	
	$I_F = 7.5\text{ A}$			0.59	-	
	$I_F = 15\text{ A}$			0.70	0.78	
Reverse current per diode	$V_R = 70\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	3.0	-	μA
		$T_A = 125\text{ }^\circ\text{C}$		1.0	-	mA
	$V_R = 100\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$		-	1000	μA
		$T_A = 125\text{ }^\circ\text{C}$		3.0	16	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: Pulse width $\leq 5\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	V30M100M	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	1.8	$^\circ\text{C/W}$
	per device		0.9	
	per device	$R_{\theta JA}^{(1)(2)}$	40	

Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient $dP_D/dT_J < 1/R_{\theta JA}$
 (2) Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V30M100M-E3/4W	1.88	4W	50/tube	Tube

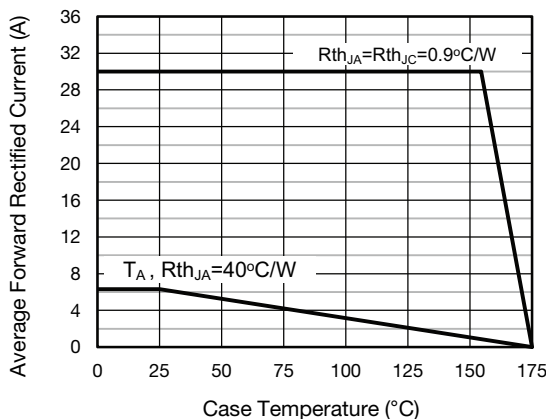
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

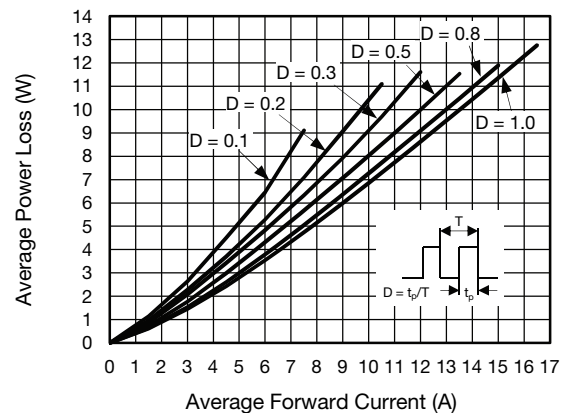


Fig. 2 - Forward Power Loss Characteristics Per Diode

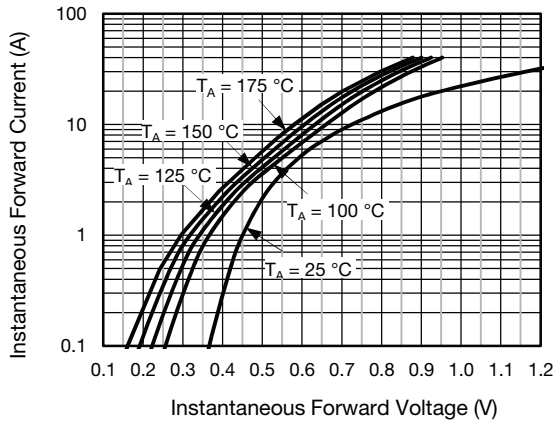


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

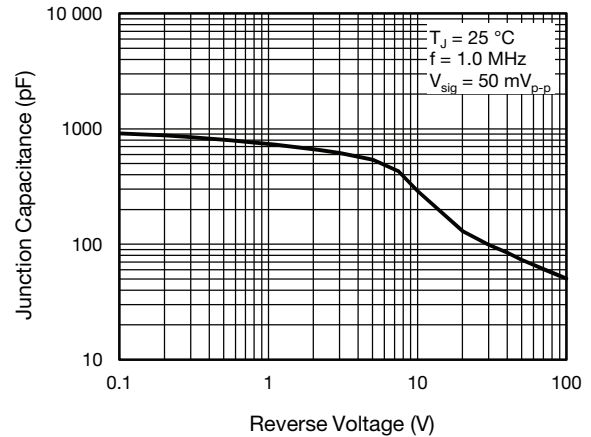


Fig. 5 - Typical Junction Capacitance Per Diode

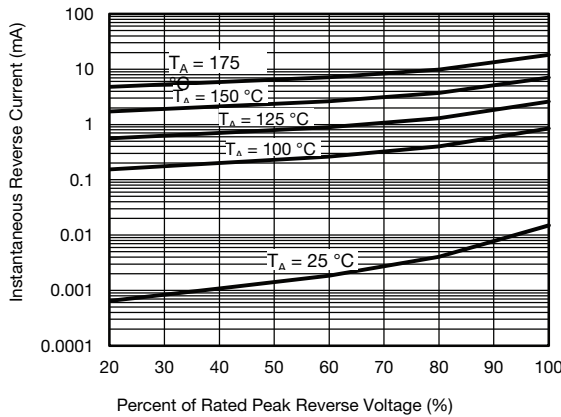


Fig. 4 - Typical Reverse Characteristics Per Diode

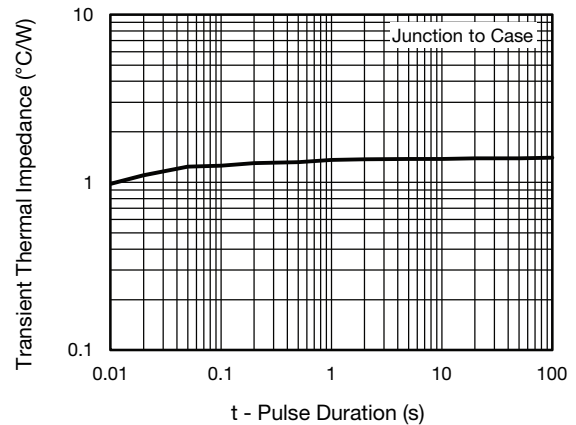
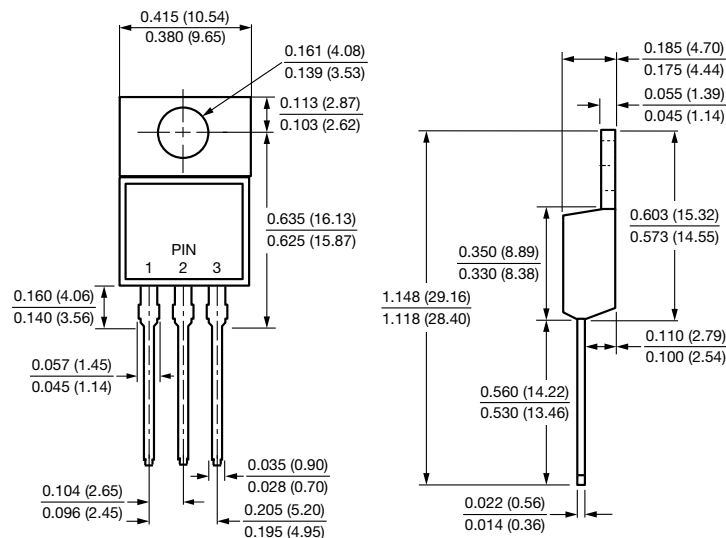


Fig. 6 - Typical Transient Thermal Impedance Per Device

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB





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